



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

#8/Comptb  
Ass't  
9/20/02

In re the Application of: **SUZUKI, Minoru et al.**

Examiner: **Kenelt PIERRE**

Serial Number: **10/014,407**

Group Art Unit: **2822**

Filed: **December 14, 2001**

P.T.O. Confirmation No.: **9744**

For. **SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING  
A SEMICONDUCTOR DEVICE**

**AMENDMENT UNDER 37 CFR §1.111**

Commissioner for Patents  
Washington, D.C. 20231

September 16, 2002

Sir:

In response to the Office Action dated June 19, 2002, please amend the above-identified application as follows:

**IN THE CLAIMS:**

Claims 1 and 2 have been amended so as to read as follows:

1. (Amended) A semiconductor device having, when one of either an N-type or P-type is defined as a first conductivity type, and the other is provided as a second conductivity type, a semiconductor substrate of the first conductivity type, the semiconductor device comprising:

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